

3.5-MHz HIGH EFFICIENCY STEP-UP CONVERTER IN CHIP SCALE PACKAGING

Check for Samples: [TPS61253](#), [TPS61254](#), [TPS61256](#), [TPS61258](#), [TPS61259](#)

FEATURES

- 93% Efficiency at 3.5MHz Operation
- 22µA Quiescent Current in Standby Mode
- 36µA Quiescent Current in Normal Operation
- Wide V_{IN} Range From 2.3V to 5.5V
- $V_{IN} \geq V_{OUT}$ Operation
- $I_{OUT} \geq 800\text{mA}$ at $V_{OUT} = 4.5\text{V}$, $V_{IN} \geq 2.65\text{V}$
- $I_{OUT} \geq 1000\text{mA}$ at $V_{OUT} = 5.0\text{V}$, $V_{IN} \geq 3.3\text{V}$
- $I_{OUT} \geq 1500\text{mA}$ (Peak) at $V_{OUT} = 5.0\text{V}$, $V_{IN} \geq 3.3\text{V}$
- $\pm 2\%$ Total DC Voltage Accuracy
- Light-Load PFM Mode
- Selectable Standby Mode or True Load Disconnect During Shutdown
- Thermal Shutdown and Overload Protection
- Only Three Surface-Mount External Components Required
- Total Solution Size <25mm²
- 9-Pin NanoFree™ (CSP) Packaging

APPLICATIONS

- Cell Phones, Smart-Phones
- Mono and Stereo APA Applications
- USB Charging Port (5V)

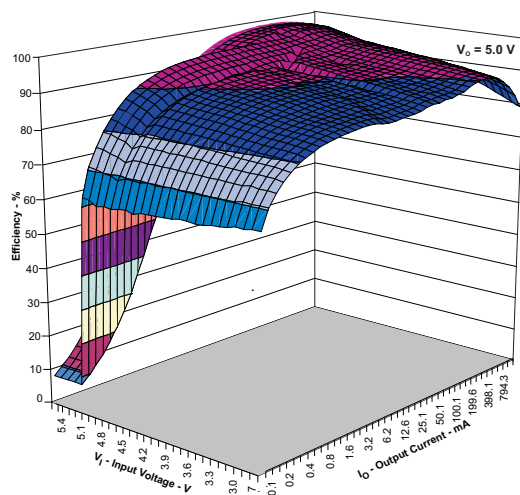


Figure 1. Efficiency vs. Load Current

DESCRIPTION

The TPS6125x device provides a power supply solution for battery-powered portable applications. Intended for low-power applications, the TPS6125x supports up to 800-mA load current from a battery discharged as low as 2.65V and allows the use of low cost chip inductor and capacitors.

With a wide input voltage range of 2.3V to 5.5V, the device supports applications powered by Li-Ion batteries with extended voltage range. Different fixed voltage output versions are available from 3.15V to 5.0V.

The TPS6125x operates at a regulated 3.5-MHz switching frequency and enters power-save mode operation at light load currents to maintain high efficiency over the entire load current range. The PFM mode extends the battery life by reducing the quiescent current to 36µA (typ) during light load operation.

In addition, the TPS6125x device can also maintain its output biased at the input voltage level. In this mode, the synchronous rectifier is current limited allowing external load (e.g. audio amplifier) to be powered with a restricted supply. In this mode, the quiescent current is reduced to 22µA. Input current in shutdown mode is less than 1µA (typ), which maximizes battery life.

The TPS6125x offers a very small solution size due to minimum amount of external components. It allows the use of small inductors and input capacitors to achieve a small solution size. During shutdown, the load is completely disconnected from the battery.

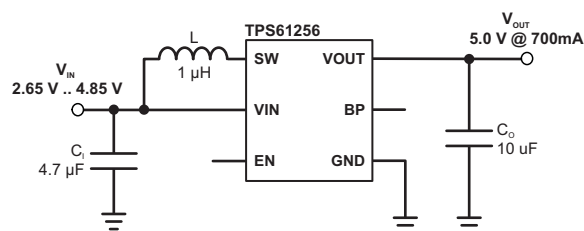


Figure 2. Smallest Solution Size Application



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

UNLESS OTHERWISE NOTED this document contains PRODUCTION DATA information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2011–2012, Texas Instruments Incorporated



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

AVAILABLE DEVICE OPTION

T _A	PART NUMBER ⁽¹⁾	OUTPUT VOLTAGE	DEVICE SPECIFIC FEATURES	ORDERING ⁽²⁾	PACKAGE MARKING CHIP CODE
–40°C to 85°C	TPS61253	5.0V	Supports 5V, up to 1500mA peak loading down to 3.3V input voltage	TPS61253YFF	SBF
	TPS61254	4.5V	Supports 4.5V/800mA loading down to 2.65V input voltage	TPS61254YFF	QWR
	TPS61255 ⁽³⁾	3.75V		TPS61255YFF	QWS
	TPS61256	5.0V	Supports 5V/900mA loading down to 3.3V input voltage	TPS61256YFF	RAV
	TPS61257 ⁽³⁾	4.3V		TPS61257YFF	RAO
	TPS61258	4.5V	Supports 4.5V, up to 1500mA peak loading down to 3.3V input voltage	TPS61258YFF	SAZ
	TPS61259	5.1V	Supports 5.1V, up to 1500mA peak loading down to 3.3V input voltage	TPS61259YFF	SAY

- (1) For detailed ordering information please check the PACKAGE OPTION ADDENDUM section at the end of this datasheet.
(2) The YFF package is available in tape and reel. Add a R suffix (e.g. TPS61254YFFR) to order quantities of 3000 parts. Add a T suffix (e.g. TPS61254YFFT) to order quantities of 250 parts.
(3) Product preview. [Contact TI factory for more information](#)

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			UNIT
Input voltage	Voltage at VIN ⁽²⁾ , VOUT ⁽²⁾ , SW ⁽²⁾ , EN ⁽²⁾ , BP ⁽²⁾	–0.3 to 7	V
Input current	Continuous average current into SW ⁽³⁾	1.8	A
	Peak current into SW ⁽⁴⁾	3.5	A
Power dissipation		Internally limited	
Temperature range	Operating temperature range, T _A ⁽⁵⁾	–40 to 85	°C
	Operating virtual junction, T _J	–40 to 150	°C
	Storage temperature range, T _{stg}	–65 to 150	°C
ESD rating ⁽⁶⁾	Human Body Model - (HBM)	2000	V
	Charge Device Model - (CDM)	1000	V
	Machine Model - (MM)	200	V

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to network ground terminal.
(3) Limit the junction temperature to 105°C for continuous operation at maximum output power.
(4) Limit the junction temperature to 125°C for 5% duty cycle operation.
(5) In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature (T_{A(max)}) is dependent on the maximum operating junction temperature (T_{J(max)}), the maximum power dissipation of the device in the application (P_{D(max)}), and the junction-to-ambient thermal resistance of the part/package in the application (θ_{JA}), as given by the following equation: T_{A(max)} = T_{J(max)} – (θ_{JA} × P_{D(max)}). To achieve optimum performance, it is recommended to operate the device with a maximum junction temperature of 105°C.
(6) The human body model is a 100-pF capacitor discharged through a 1.5-kΩ resistor into each pin. The machine model is a 200-pF capacitor discharged directly into each pin.

RECOMMENDED OPERATING CONDITIONS

			MIN	NOM	MAX	UNIT
V_I	Input voltage range	TPS61253	2.65 ⁽¹⁾		4.85	V
		TPS61254	2.5		4.35	
		TPS61256	2.5		4.85	
		TPS61257	2.5		4.15	
		TPS61258	2.65 ⁽¹⁾		4.35	
		TPS61259	2.65 ⁽¹⁾		4.85	
R_L	Minimum resistive load for start-up	TPS6125X	55			Ω
L	Inductance		0.7	1.0	2.9	μH
C_O	Output capacitance		3.5	5	50	μF
T_A	Ambient temperature		–40		85	$^{\circ}\text{C}$
T_J	Operating junction temperature		–40		125	$^{\circ}\text{C}$

(1) Up to 1000mA peak output current.

THERMAL INFORMATION

THERMAL METRIC ⁽¹⁾		TPS6125x	UNIT
		YFF	
		9 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	110	$^{\circ}\text{C}/\text{W}$
θ_{JCTop}	Junction-to-case (top) thermal resistance		
θ_{JB}	Junction-to-board thermal resistance	35	
ψ_{JT}	Junction-to-top characterization parameter		
ψ_{JB}	Junction-to-board characterization parameter	50	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance		

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

ELECTRICAL CHARACTERISTICS

Minimum and maximum values are at $V_{IN} = 2.3\text{V}$ to 5.5V , $V_{OUT} = 4.5\text{V}$ (or V_{IN} , whichever is higher), $EN = 1.8\text{V}$, $T_A = -40^{\circ}\text{C}$ to 85°C ; Circuit of Parameter Measurement Information section (unless otherwise noted). Typical values are at $V_{IN} = 3.6\text{V}$, $V_{OUT} = 4.5\text{V}$, $EN = 1.8\text{V}$, $T_A = 25^{\circ}\text{C}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I_Q	Operating quiescent current into V_{IN}	$I_{OUT} = 0\text{mA}$, $V_{IN} = 3.6\text{V}$ $EN = V_{IN}$, $BP = \text{GND}$ Device not switching		30	45	μA
	Operating quiescent current into V_{OUT}			7	15	μA
	Standby mode quiescent current into V_{IN}	$I_{OUT} = 0\text{mA}$, $V_{IN} = V_{OUT} = 3.6\text{V}$ $EN = \text{GND}$, $BP = V_{IN}$ Device not switching		11	20	μA
	Standby mode quiescent current into V_{OUT}			9.5	15	μA
I_{SD}	Shutdown current	TPS6125x $EN = \text{GND}$, $BP = \text{GND}$		0.85	5.0	μA
V_{UVLO}	Under-voltage lockout threshold	TPS6125x Falling		2.0	2.1	V
		TPS6125x Hysteresis		0.1		V

ELECTRICAL CHARACTERISTICS (continued)

Minimum and maximum values are at $V_{IN} = 2.3V$ to $5.5V$, $V_{OUT} = 4.5V$ (or V_{IN} , whichever is higher), $EN = 1.8V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$; Circuit of Parameter Measurement Information section (unless otherwise noted). Typical values are at $V_{IN} = 3.6V$, $V_{OUT} = 4.5V$, $EN = 1.8V$, $T_A = 25^{\circ}C$ (unless otherwise noted).

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
ENABLE, BYPASS								
V _{IL}	Low-level input voltage	TPS6125x					0.4	V
V _{IH}	High-level input voltage				1.0			V
I _{lkg}	Input leakage current		Input connected to GND or V _{IN}				0.5	μA
OUTPUT								
V _{OUT}	Regulated DC output voltage	TPS61253	2.3V ≤ V _{IN} ≤ 4.85V, I _{OUT} = 0mA PWM operation. Open Loop	4.92	5	5.08	V	
			3.3V ≤ V _{IN} ≤ 4.85V, 0mA ≤ I _{OUT} ≤ 1000mA PFM/PWM operation	4.85	5	5.2		
			3.3V ≤ V _{IN} ≤ 4.85V, 0mA ≤ I _{OUT} ≤ 1500mA PFM/PWM operation Pulsed load test; Pulse width ≤ 20ms; Duty cycle ≤ 10%	4.75	5	5.2		
	Regulated DC output voltage	TPS61254	2.3V ≤ V _{IN} ≤ 4.35V, I _{OUT} = 0mA PWM operation. Open Loop	4.43	4.5	4.57	V	
			2.65V ≤ V _{IN} ≤ 4.35V, 0mA ≤ I _{OUT} ≤ 800mA PFM/PWM operation	4.4	4.5	4.65		
	Regulated DC output voltage	TPS61256	2.3V ≤ V _{IN} ≤ 4.85V, I _{OUT} = 0mA PWM operation. Open Loop	4.92	5	5.08	V	
			2.65V ≤ V _{IN} ≤ 4.85V, 0mA ≤ I _{OUT} ≤ 700mA PFM/PWM operation	4.9	5	5.2		
	Regulated DC output voltage	TPS61257	2.3V ≤ V _{IN} ≤ 4.15V, I _{OUT} = 0mA PWM operation. Open loop.	4.23	4.3	4.37	V	
			2.65V ≤ V _{IN} ≤ 4.15V, 0mA ≤ I _{OUT} ≤ 800mA PFM/PWM operation	4.2	4.3	4.45		
	Regulated DC output voltage	TPS61258	2.3V ≤ V _{IN} ≤ 4.35V, I _{OUT} = 0mA PWM operation. Open Loop	4.43	4.5	4.57	V	
			3.3V ≤ V _{IN} ≤ 4.35V, 0mA ≤ I _{OUT} ≤ 1500mA PFM/PWM operation Pulsed load test; Pulse width ≤ 20ms; Duty cycle ≤ 10%	4.3	4.5	4.65		
	Regulated DC output voltage	TPS61259	2.3V ≤ V _{IN} ≤ 4.85V, I _{OUT} = 0mA PWM operation. Open Loop	5.02	5.1	5.18	V	
			3.4V ≤ V _{IN} ≤ 4.85V, 0mA ≤ I _{OUT} ≤ 1500mA PFM/PWM operation Pulsed load test; Pulse width ≤ 20ms; Duty cycle ≤ 10%	4.75	5.1	5.3		
ΔV _{OUT}	Power-save mode output ripple voltage	TPS61254 TPS61258	PFM operation, I _{OUT} = 1mA		45	mVpk		
	Standby mode output ripple voltage		EN = GND, BP = V _{IN} , I _{OUT} = 0mA	80				
	PWM mode output ripple voltage		PWM operation, I _{OUT} = 200mA	20				
	Power-save mode output ripple voltage	TPS61253 TPS61256 TPS61259	PFM operation, I _{OUT} = 1mA		50	mVpk		
	Standby mode output ripple voltage		EN = GND, BP = V _{IN} , I _{OUT} = 0mA	80				
	PWM mode output ripple voltage		PWM operation, I _{OUT} = 200mA	20				

ELECTRICAL CHARACTERISTICS (continued)

Minimum and maximum values are at $V_{IN} = 2.3V$ to $5.5V$, $V_{OUT} = 4.5V$ (or V_{IN} , whichever is higher), $EN = 1.8V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$; Circuit of Parameter Measurement Information section (unless otherwise noted). Typical values are at $V_{IN} = 3.6V$, $V_{OUT} = 4.5V$, $EN = 1.8V$, $T_A = 25^{\circ}C$ (unless otherwise noted).

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SWITCH							
r _{DS(on)}	High-side MOSFET on resistance	TPS6125x		170			mΩ
	Low-side MOSFET on resistance			100			
I _{lkg}	Reverse leakage current into VOUT	TPS6125x	EN = GND, BP = GND	3.5			μA
I _{LIM}	Switch valley current limit	TPS61253 TPS61258 TPS61259	EN = V _{IN} , BP = GND. Open Loop	3300	3620	3900	mA
		TPS61254 TPS61256 TPS61257	EN = V _{IN} , BP = GND. Open Loop	1900	2150	2400	
	Pre-charge mode current limit (linear mode)	TPS6125x	EN = GND, BP = V _{IN}	165	215	265	mA
	Overtemperature protection		TPS6125x		140		
Overtemperature hysteresis				20			°C
OSCILLATOR							
f _{OSC}	Oscillator frequency	TPS6125x	V _{IN} = 3.6V V _{OUT} = 4.5V	3.5			MHz
TIMING							
Start-up time		TPS6125x	BP = GND, I _{OUT} = 0mA. Time from active EN to start switching	70			μs
		TPS61253 TPS61254 TPS61256 TPS61258 TPS61259	BP = GND, I _{OUT} = 0mA. Time from active EN to V _{OUT}	400			μs

PIN ASSIGNMENTS

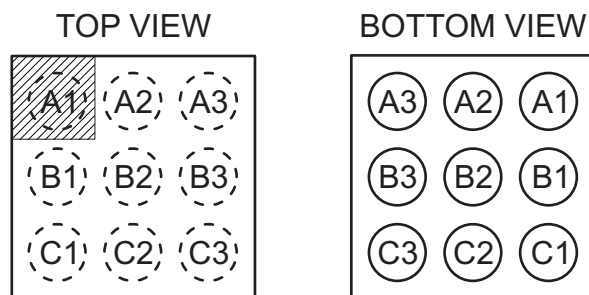
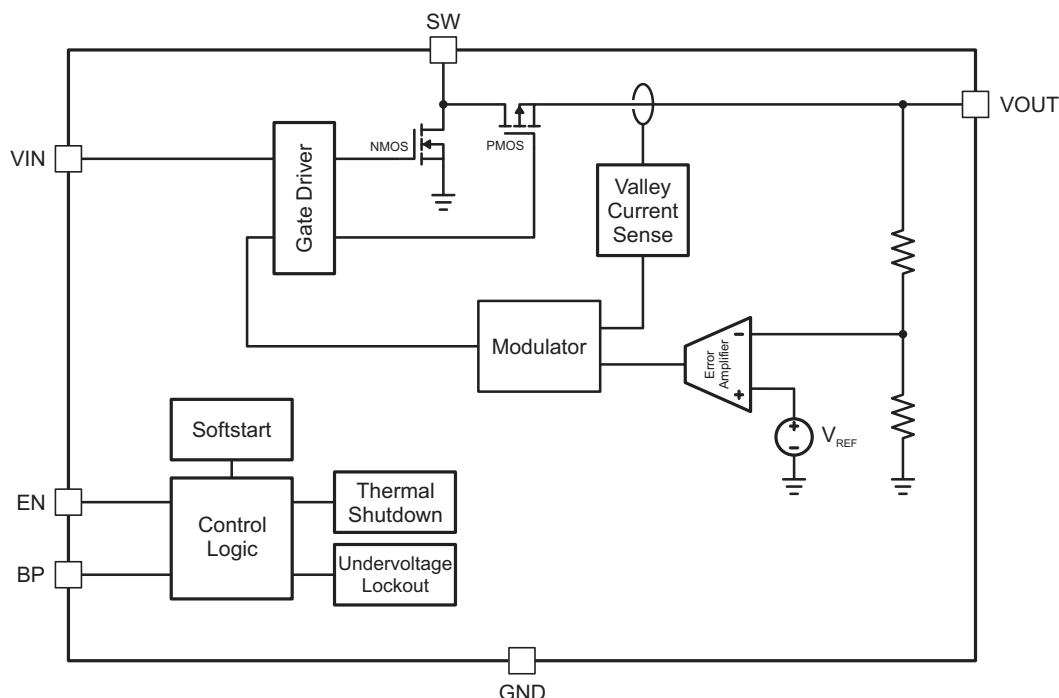


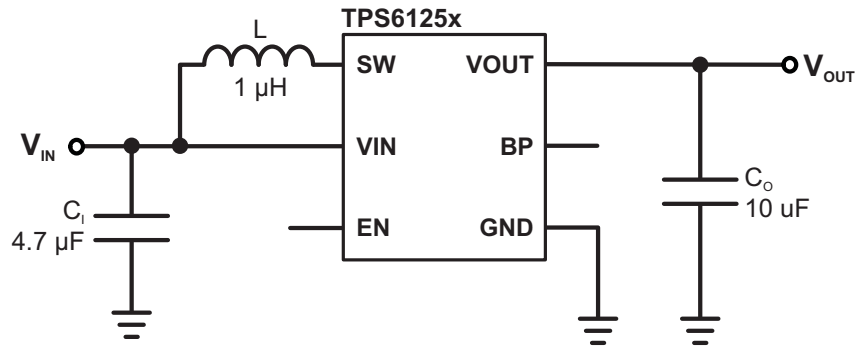
Table 1. TERMINAL FUNCTIONS

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
BP	C3	I	<p>This is the mode selection pin of the device and is only of relevance when the device is disabled (EN = Low). This pin must not be left floating and must be terminated. Refer to Table 3 for more details.</p> <p>BP = Low: The device is in true shutdown mode.</p> <p>BP = High: The output is biased at the input voltage level with a maximum load current capability of ca. 150mA. In standby mode, the device only consumes a standby current of 22µA (typ).</p>
EN	B3	I	This is the enable pin of the device. Connecting this pin to ground forces the device into shutdown mode. Pulling this pin high enables the device. This pin must not be left floating and must be terminated.
GND	C1, C2		Ground pin.
SW	B1, B2	I/O	This is the switch pin of the converter and is connected to the drain of the internal Power MOSFETs.
VIN	A3	I	Power supply input.
VOUT	A1, A2	O	Boost converter output.

FUNCTIONAL BLOCK DIAGRAM



PARAMETER MEASUREMENT INFORMATION



	EN	BP
Shutdown, True Load Disconnect (SD)	0	0
Standby Mode, Output Pre-Biased (SM)	0	1
Boost Operating Mode (BST)	1	X

Table 2. List of Components

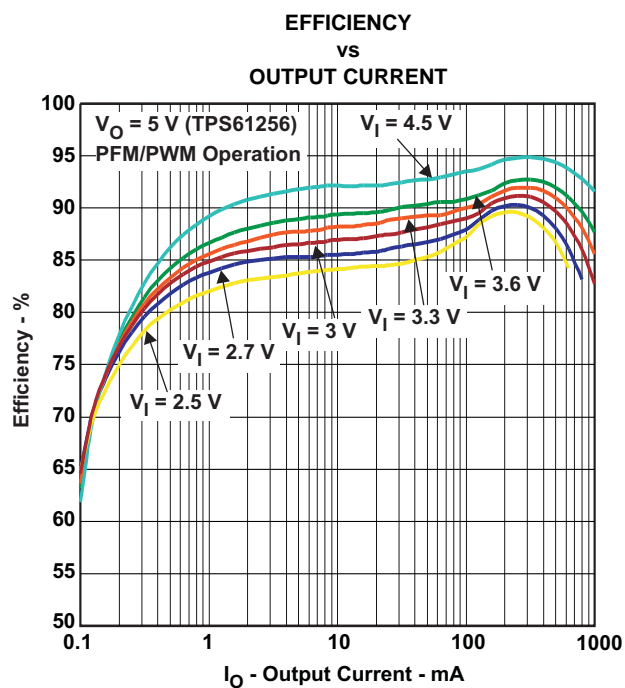
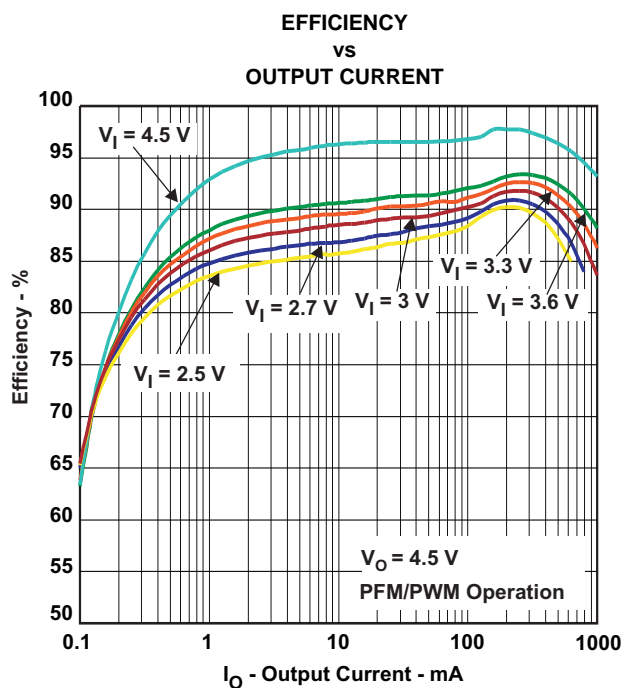
REFERENCE	DESCRIPTION	PART NUMBER, MANUFACTURER
L ⁽¹⁾	1.0µH, 1.8A, 48mΩ, 3.2 x 2.5 x 1.0mm max. height	LQM32PN1R0MG0, muRata
L ⁽²⁾	1.0µH, 3.7A, 37mΩ, 3.2 x 2.5 x 1.2mm max. height	DFE322512C, TOKO
C _I	4.7µF, 6.3V, 0402, X5R ceramic	GRM155R60J475M, muRata
C _O	10µF, 6.3V, 0603, X5R ceramic	GRM188R60J106ME84, muRata

- (1) Inductor used to characterize TPS61254YFF, TPS61255YFF, TPS61256YFF and TPS61257YFF devices.
(2) Inductor used to characterize TPS61253YFF, TPS61258YFF and TPS61259YFF devices.

TYPICAL CHARACTERISTICS

TABLE OF GRAPHS

			FIGURE
η	Efficiency	vs Output current	3, 4, 5, 7
		vs Input voltage	6
V_O	DC output voltage	vs Output current	8, 9, 10, 11, 12, 16
		vs Input voltage	13
I_O	Maximum output current	vs Input voltage	14, 15
ΔV_O	Peak-to-peak output ripple voltage	vs Output current	17, 18, 19
I_{CC}	Supply current	vs Input voltage	20, 21
I_{LIM}	DC pre-charge current	vs Differential input-output voltage	22, 23
	Valley current limit	vs Temperature	24, 25
$r_{DS(on)}$	MOSFET $r_{DS(on)}$	vs Temperature	26
	PFM operation		27
	PWM operation		28
	Combined line/load transient response		29
	Load transient response		30, 32
	AC load transient response		31, 33
	Start-up		34, 35



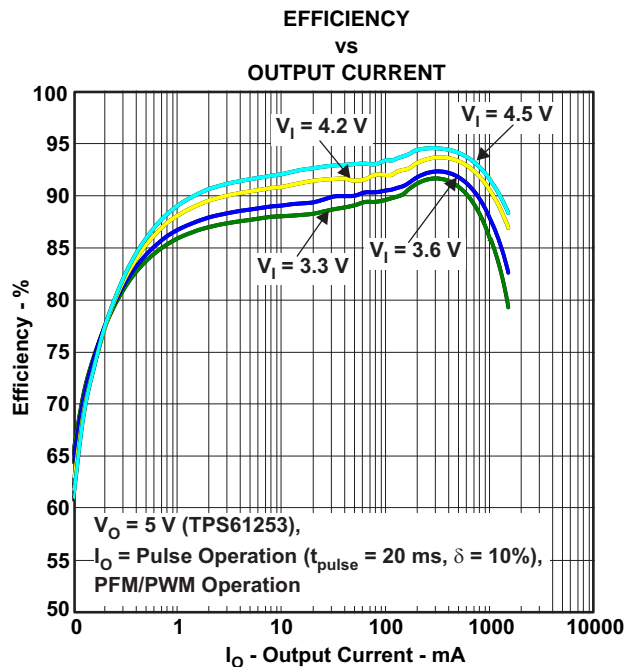


Figure 5.

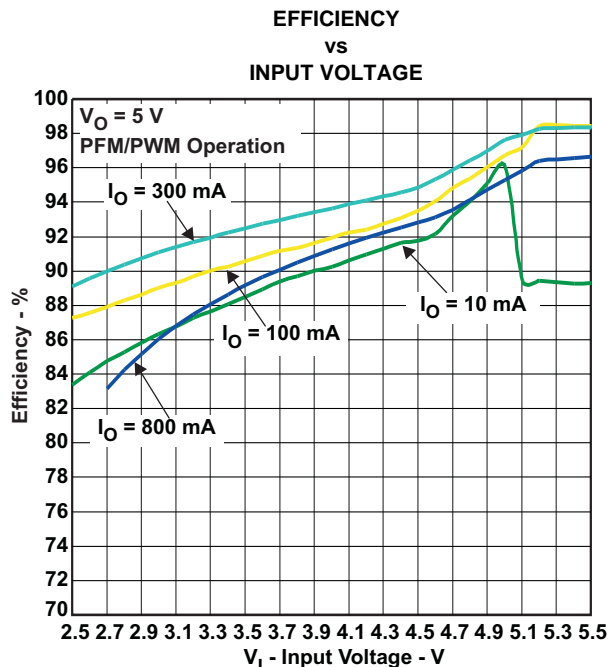


Figure 6.

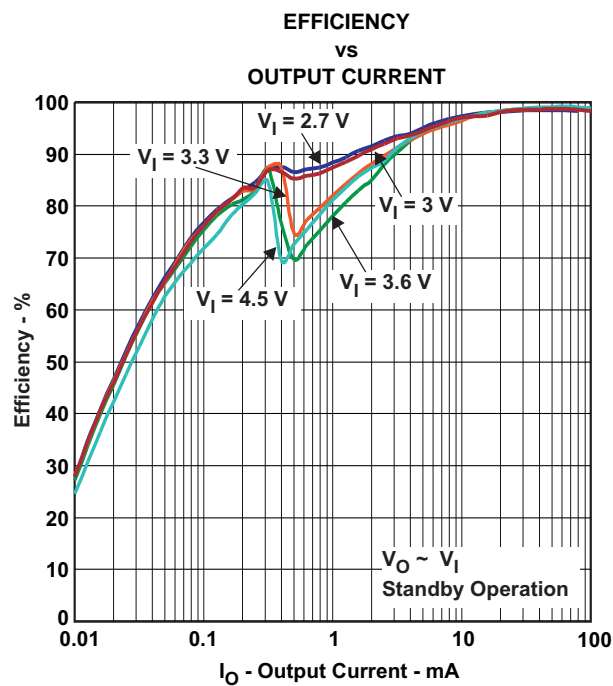


Figure 7.

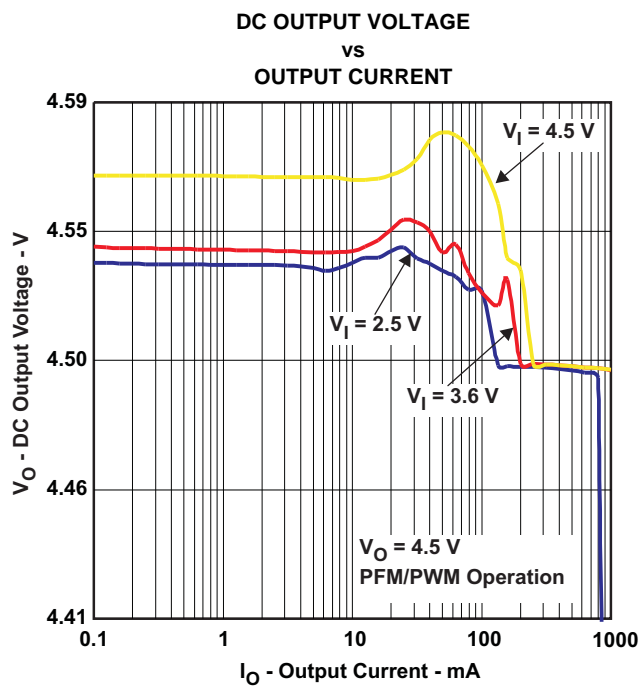


Figure 8.

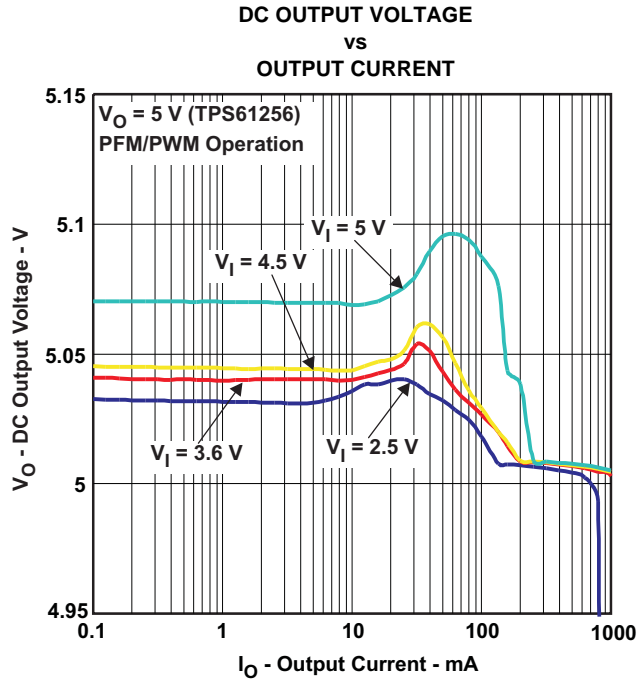


Figure 9.

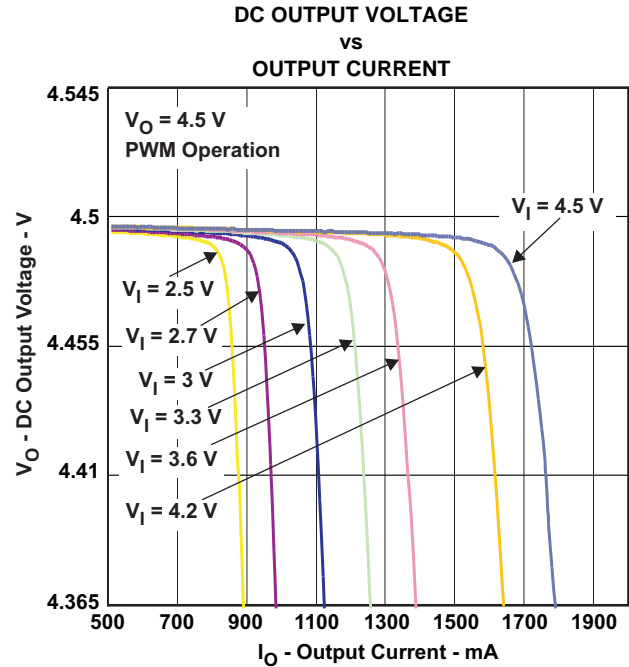


Figure 10.

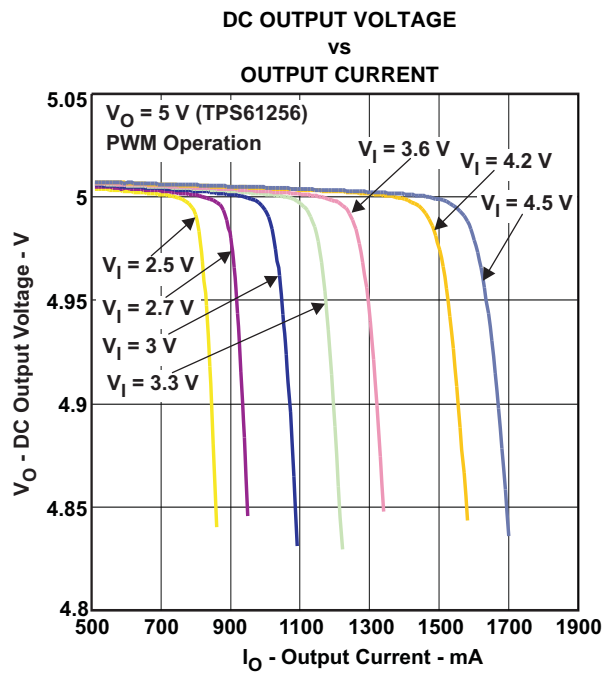


Figure 11.

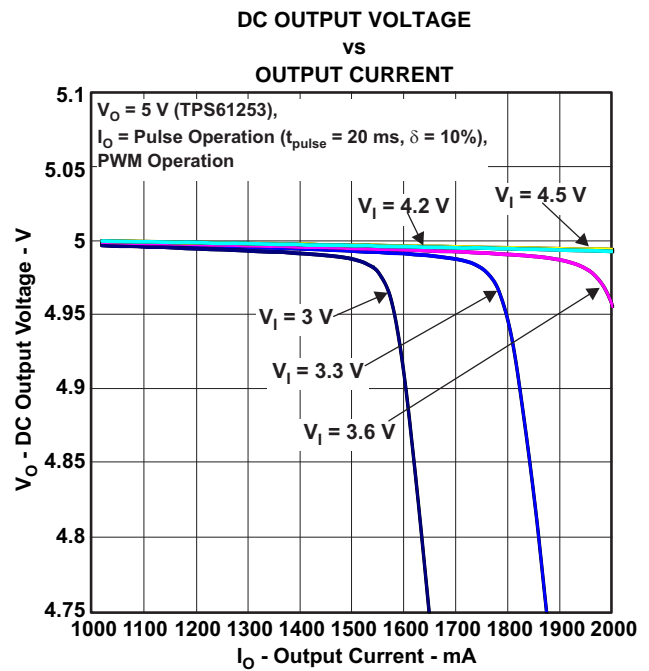


Figure 12.

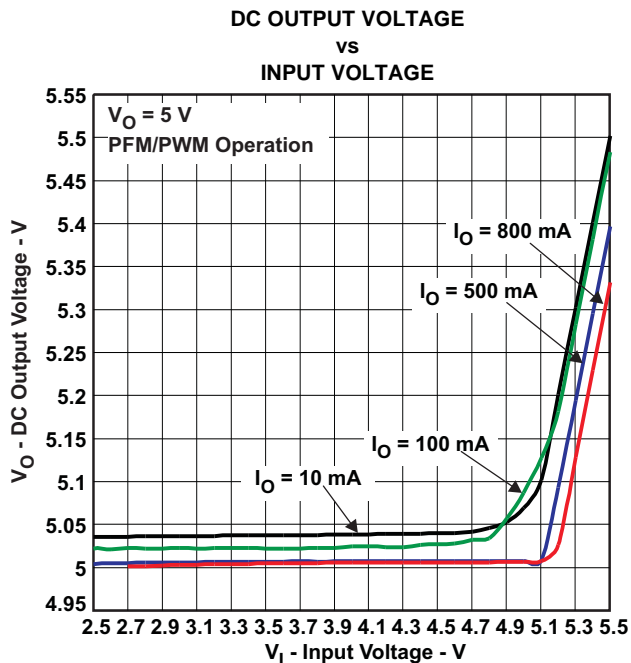


Figure 13.

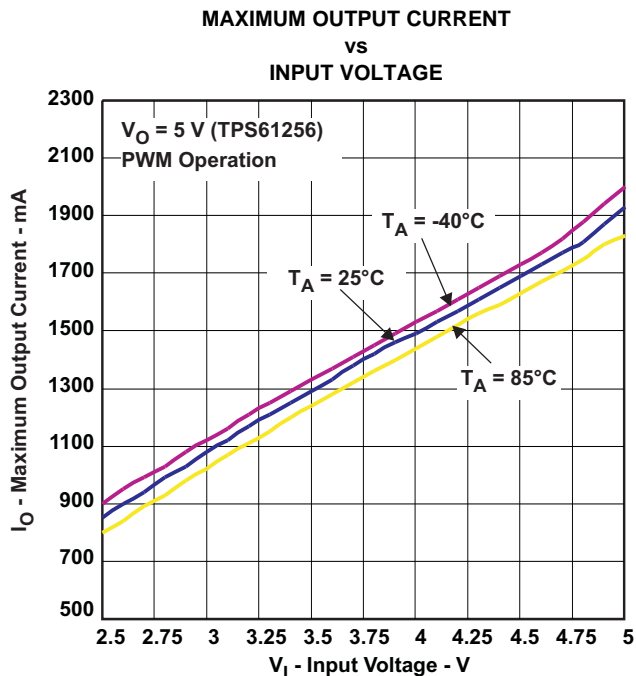


Figure 14.

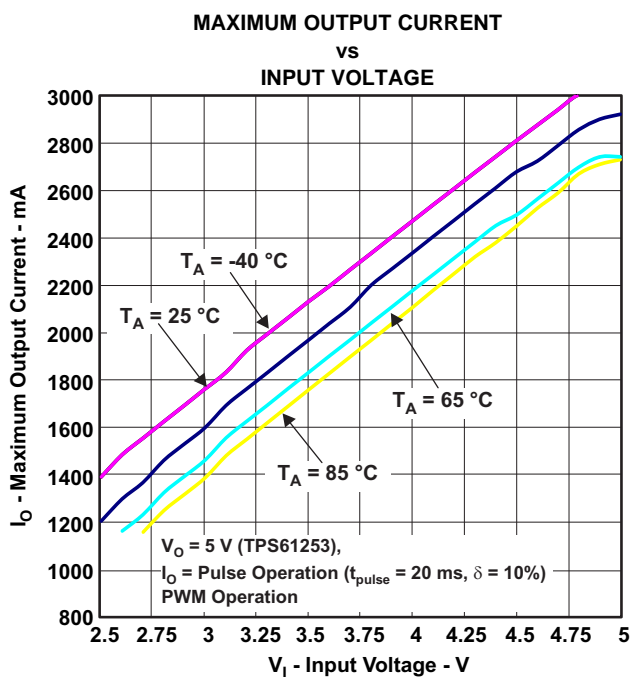


Figure 15.

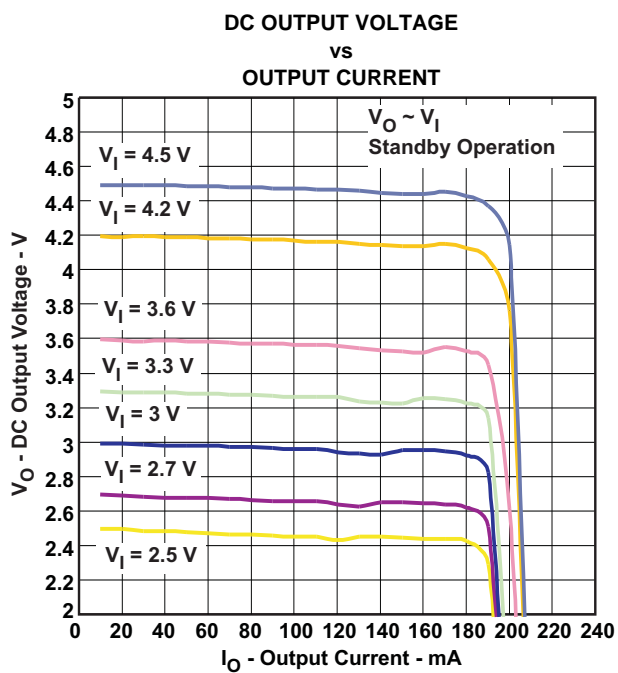


Figure 16.

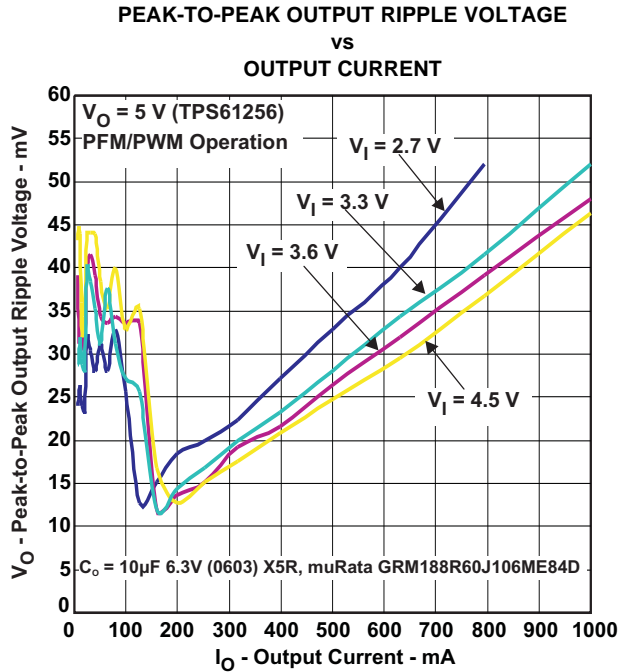


Figure 17.

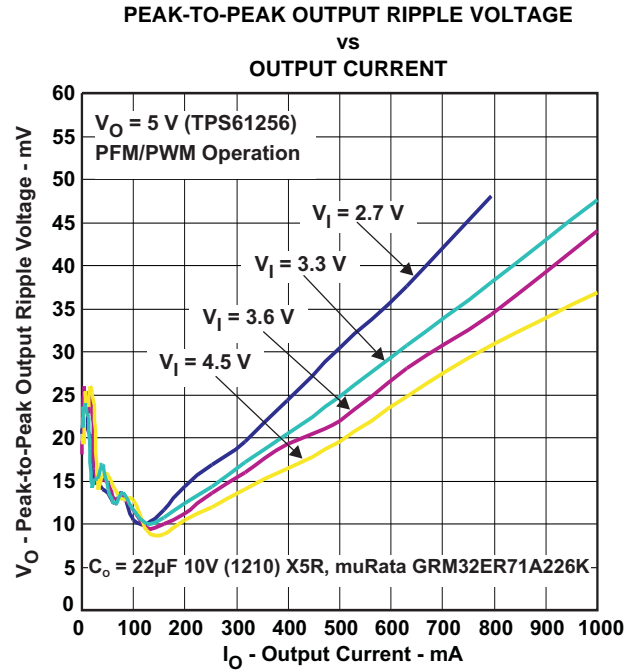


Figure 18.

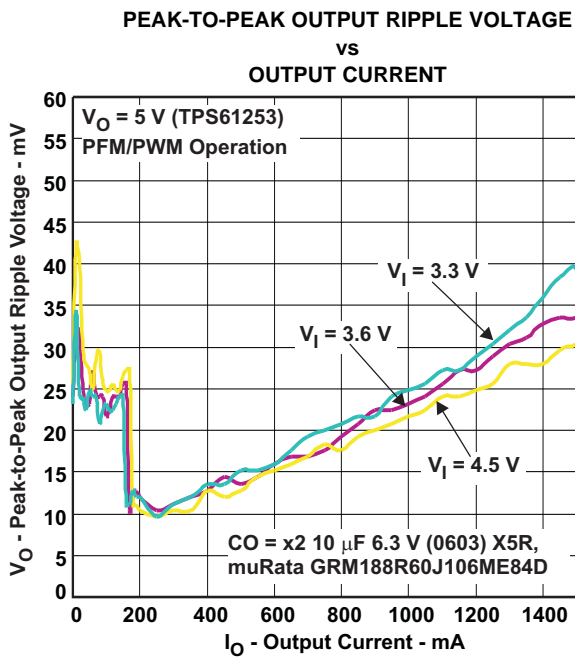


Figure 19.

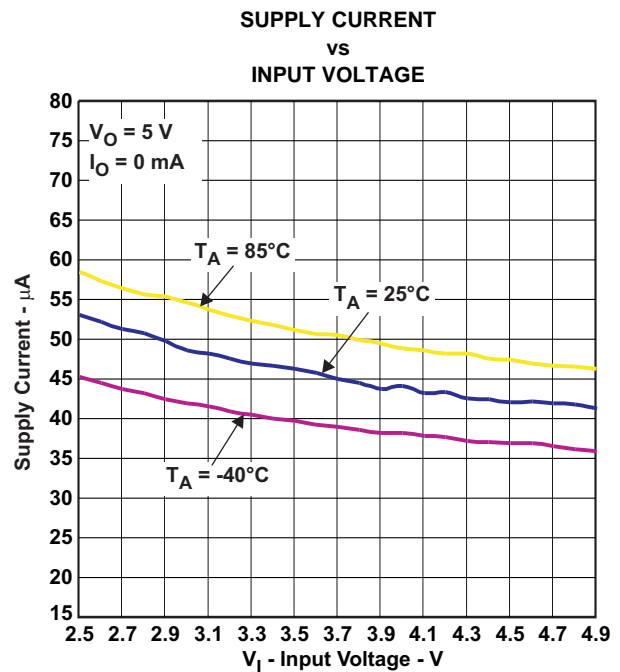


Figure 20.

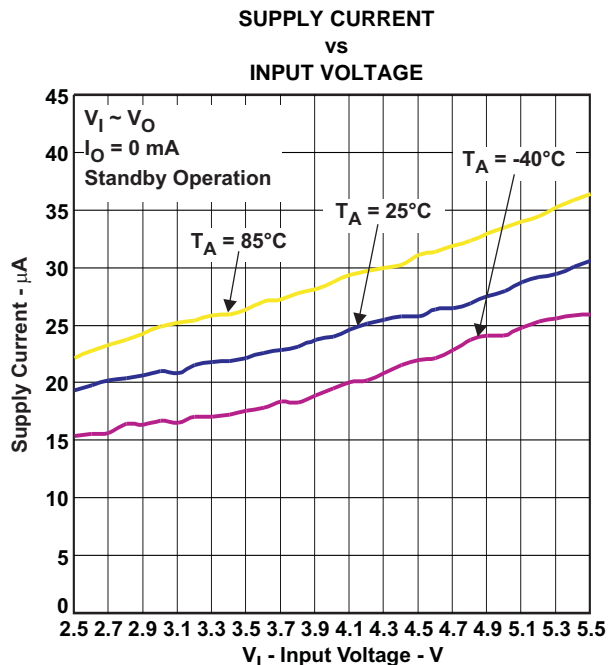


Figure 21.

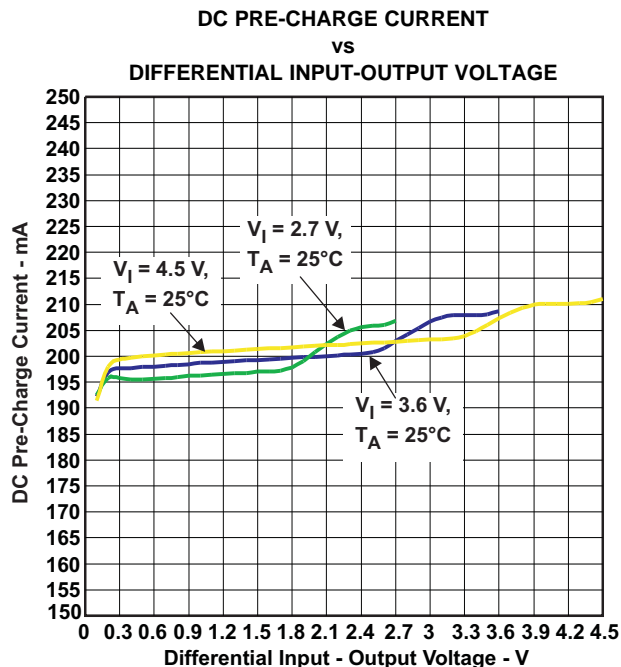


Figure 22.

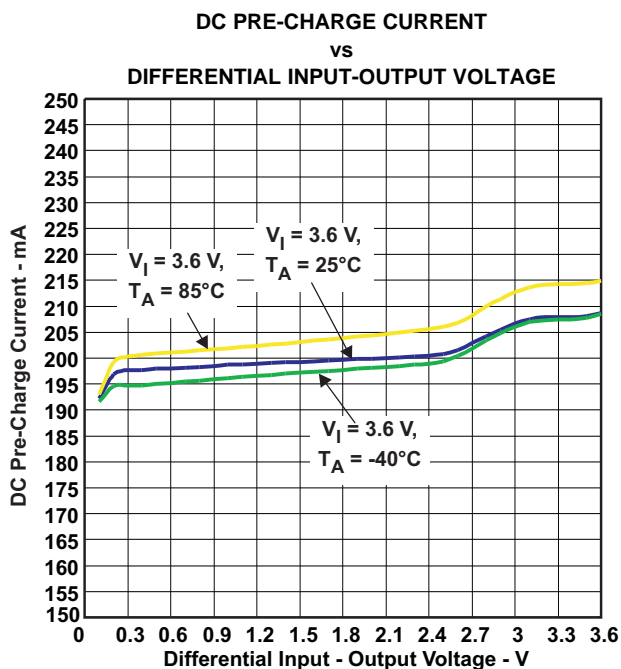


Figure 23.

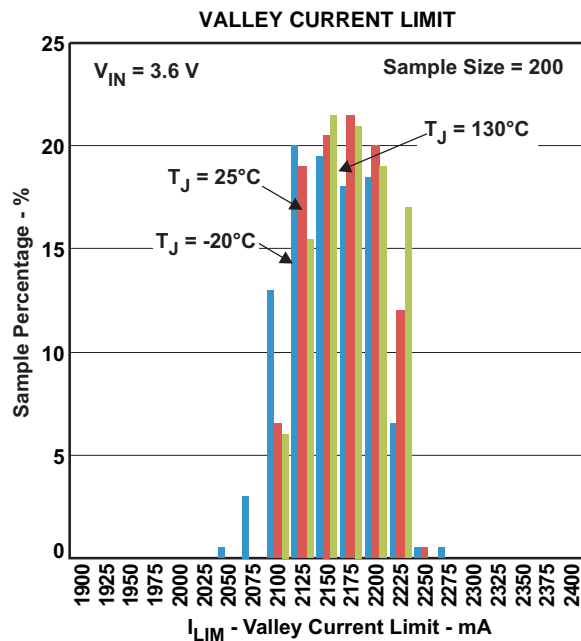


Figure 24.

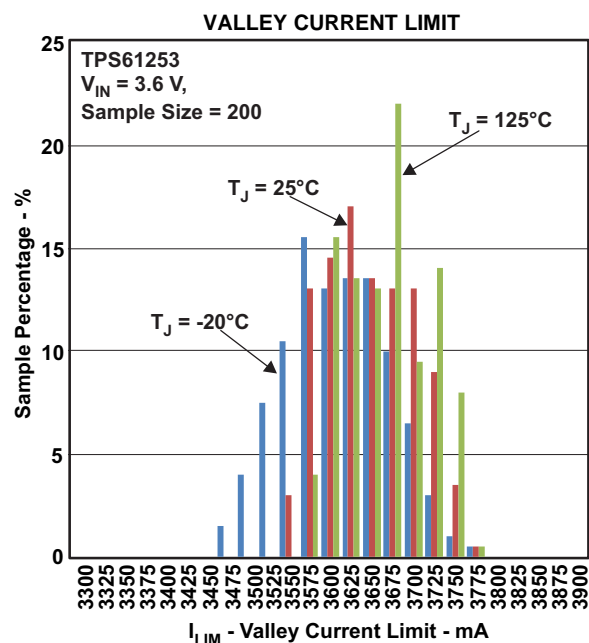


Figure 25.

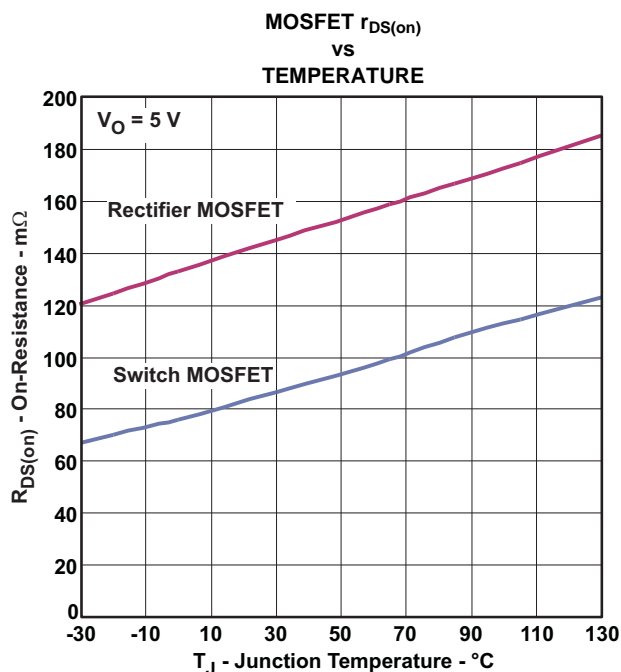


Figure 26.

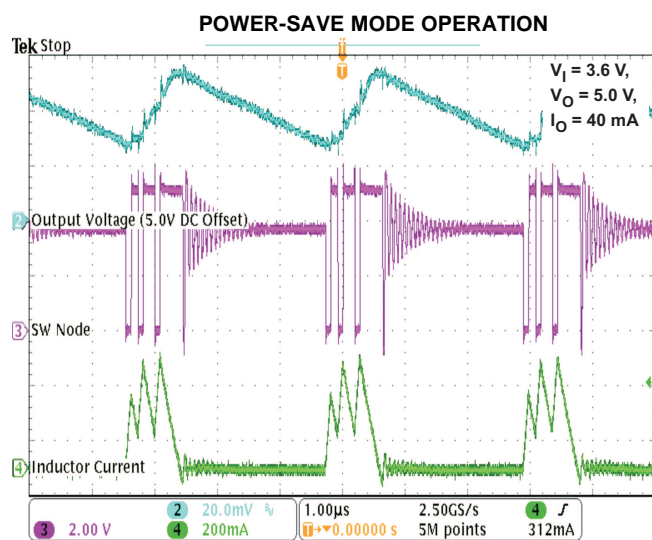


Figure 27.

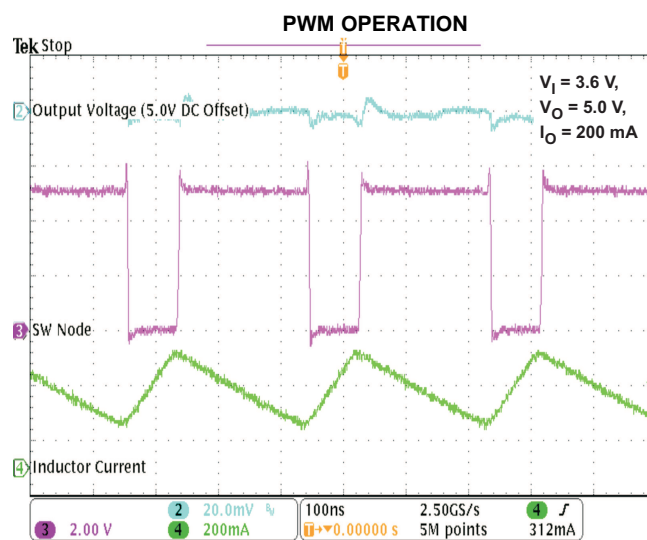


Figure 28.

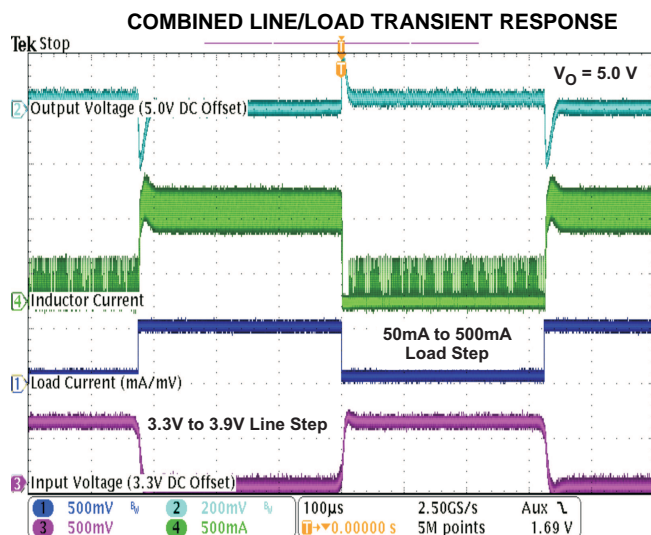


Figure 29.

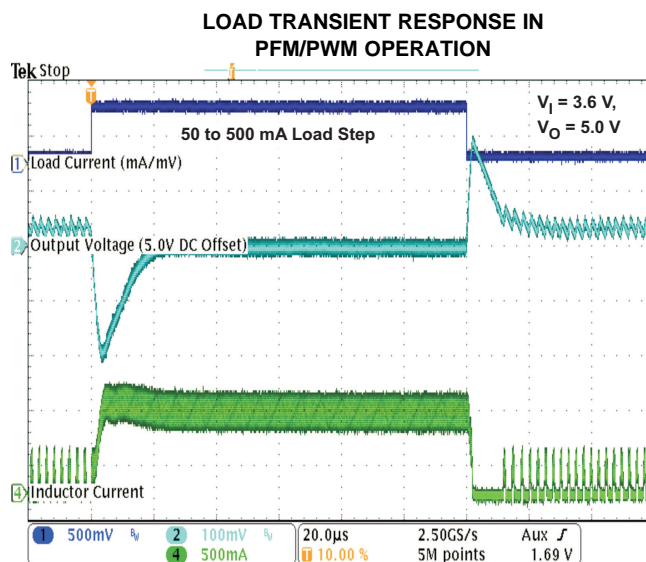


Figure 30.

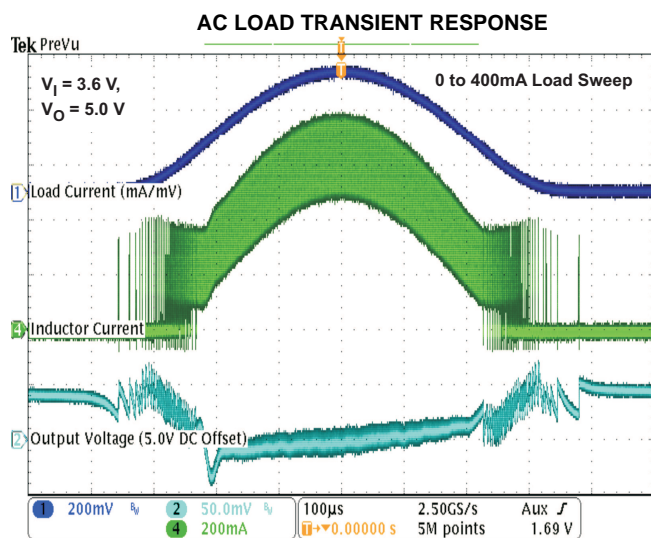


Figure 31.

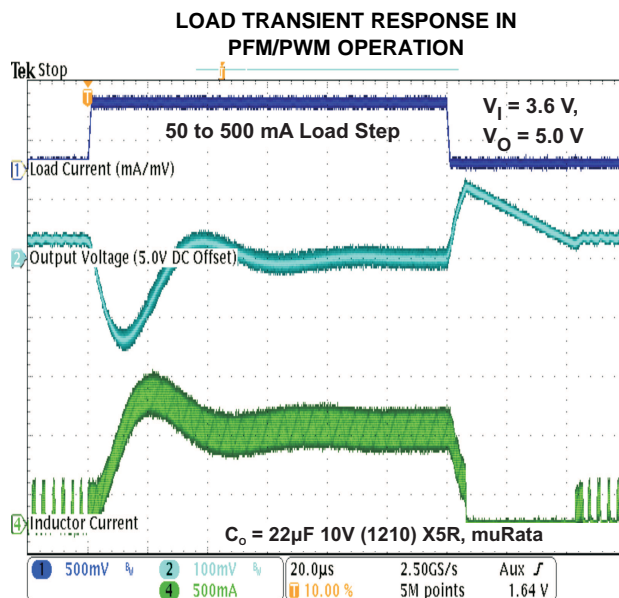


Figure 32.

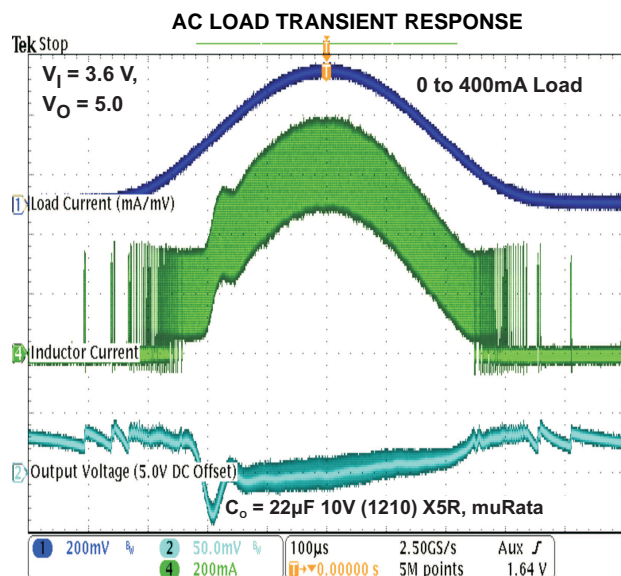


Figure 33.

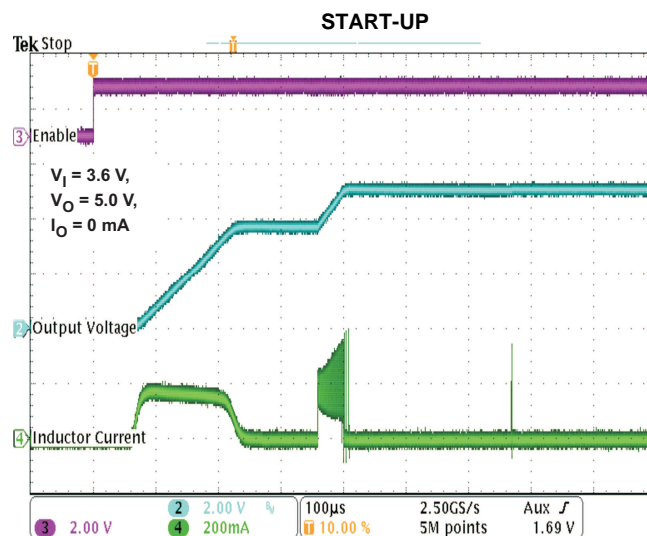


Figure 34.

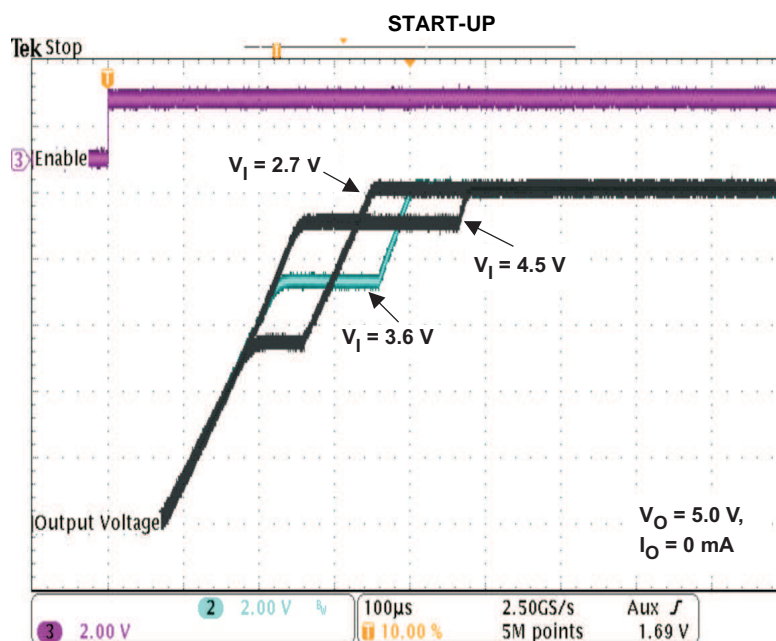


Figure 35.

DETAILED DESCRIPTION

OPERATION

The TPS6125x synchronous step-up converter typically operates at a quasi-constant 3.5-MHz frequency pulse width modulation (PWM) at moderate to heavy load currents. At light load currents, the TPS6125x converter operates in power-save mode with pulse frequency modulation (PFM).

During PWM operation, the converter uses a novel quasi-constant on-time valley current mode control scheme to achieve excellent line/load regulation and allows the use of a small ceramic inductor and capacitors. Based on the V_{IN}/V_{OUT} ratio, a simple circuit predicts the required on-time.

At the beginning of the switching cycle, the low-side N-MOS switch is turned-on and the inductor current ramps up to a peak current that is defined by the on-time and the inductance. In the second phase, once the on-timer has expired, the rectifier is turned-on and the inductor current decays to a preset valley current threshold. Finally, the switching cycle repeats by setting the on timer again and activating the low-side N-MOS switch.

In general, a dc/dc step-up converter can only operate in "true" boost mode, i.e. the output "boosted" by a certain amount above the input voltage. The TPS6125x device operates differently as it can smoothly transition in and out of zero duty cycle operation. Therefore the output can be kept as close as possible to its regulation limits even though the converter is subject to an input voltage that tends to be excessive. In this operation mode, the output current capability of the regulator is limited to ca. 150mA. Refer to the typical characteristics section (DC Output Voltage vs. Input Voltage) for further details.

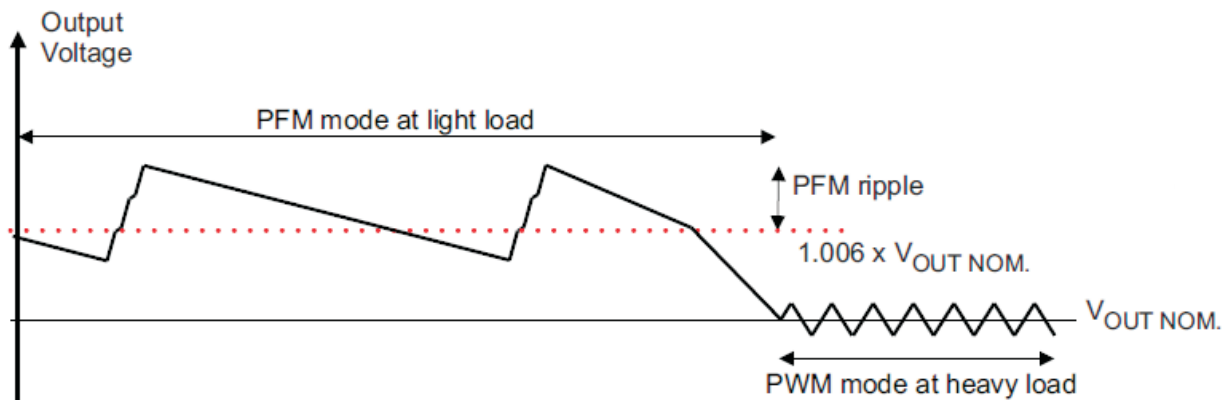
The current mode architecture with adaptive slope compensation provides excellent transient load response, requiring minimal output filtering. Internal soft-start and loop compensation simplifies the design process while minimizing the number of external components.

POWER-SAVE MODE

The TPS6125X integrates a power-save mode to improve efficiency at light load. In power save mode the converter only operates when the output voltage trips below a set threshold voltage.

It ramps up the output voltage with several pulses and goes into power save mode once the output voltage exceeds the set threshold voltage.

The PFM mode is left and PWM mode entered in case the output current can not longer be supported in PFM mode.



STANDBY MODE

The TPS6125x device is able to maintain its output biased at the input voltage level. In so called standby mode (EN = 0, BP = 1), the synchronous rectifier is current limited to ca. 150mA allowing an external load (e.g. audio amplifier) to be powered with a restricted supply. The output voltage is slightly reduced due to voltage drop across the rectifier MOSFET and the inductor DC resistance. The device consumes only a standby current of 22µA (typ).

Table 3. Operating Mode Control

OPERATING MODE	EN	BP
Shutdown, True Load Disconnect (SD)	0	0
Standby Mode, Output Pre-Biased (SM)	0	1
Boost Operating Mode (BST)	1	0
	1	1

CURRENT LIMIT OPERATION

The TPS6125x device employs a valley current limit sensing scheme. Current limit detection occurs during the off-time by sensing of the voltage drop across the synchronous rectifier.

The output voltage is reduced as the power stage of the device operates in a constant current mode. The maximum continuous output current ($I_{OUT(CL)}$), before entering current limit (CL) operation, can be defined by Equation 1.

$$I_{OUT(CL)} = (1 - D) \cdot (I_{VALLEY} + \frac{1}{2} \Delta I_L) \quad (1)$$

The duty cycle (D) can be estimated by Equation 2

$$D = 1 - \frac{V_{IN} \cdot \eta}{V_{OUT}} \quad (2)$$

and the peak-to-peak current ripple (ΔI_L) is calculated by Equation 3

$$\Delta I_L = \frac{V_{IN}}{L} \cdot \frac{D}{f} \quad (3)$$

The output current, $I_{OUT(DC)}$, is the average of the rectifier ripple current waveform. When the load current is increased such that the lower peak is above the current limit threshold, the off-time is increased to allow the current to decrease to this threshold before the next on-time begins (so called frequency fold-back mechanism). When the current limit is reached the output voltage decreases during further load increase.

Figure 36 illustrates the inductor and rectifier current waveforms during current limit operation.

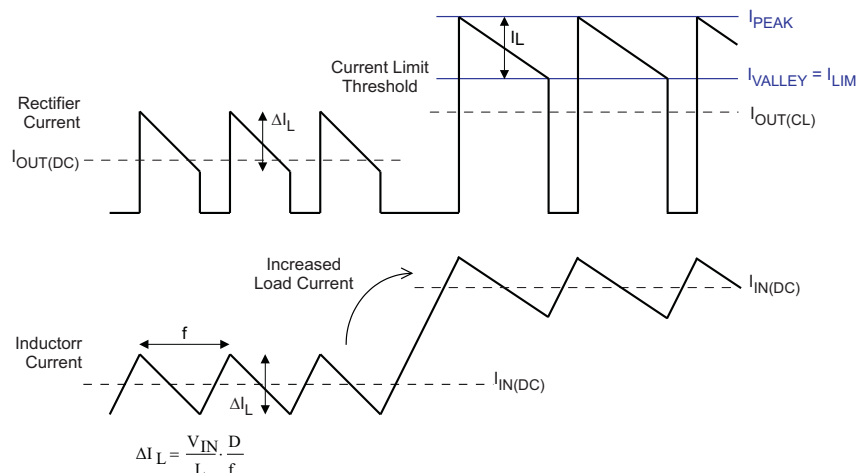


Figure 36. Inductor/Rectifier Currents in Current Limit Operation

ENABLE

The TPS6125x device starts operation when EN is set high and starts up with the soft-start sequence. For proper operation, the EN pin must be terminated and must not be left floating.

Pulling the EN and BP pins low forces the device in shutdown, with a shutdown current of typically 1 μ A. In this mode, true load disconnect between the battery and load prevents current flow from V_{IN} to V_{OUT} , as well as reverse flow from V_{OUT} to V_{IN} .

Pulling the EN pin low and the BP pin high forces the device in standby mode, refer to the [STANDBY MODE](#) section for more details.

LOAD DISCONNECT AND REVERSE CURRENT PROTECTION

Regular boost converters do not disconnect the load from the input supply and therefore a connected battery will be discharge during shutdown. The advantage of TPS6125x is that this converter is disconnecting the output from the input of the power supply when it is disabled (so called true shutdown mode). In case of a connected battery it prevents it from being discharge during shutdown of the converter.

SOFTSTART

The TPS6125x device has an internal softstart circuit that limits the inrush current during start-up. The first step in the start-up cycle is the pre-charge phase. During pre-charge, the rectifying switch is turned on until the output capacitor is charged to a value close to the input voltage. The rectifying switch is current limited (approx. 200mA) during this phase. This mechanism is used to limit the output current under short-circuit condition.

Once the output capacitor has been biased to the input voltage, the converter starts switching. The soft-start system progressively increases the on-time as a function of the input-to-output voltage ratio. As soon as the output voltage is reached, the regulation loop takes control and full current operation is permitted.

UNDERVOLTAGE LOCKOUT

The under voltage lockout circuit prevents the device from malfunctioning at low input voltages and the battery from excessive discharge. It disables the output stage of the converter once the falling V_{IN} trips the under-voltage lockout threshold V_{UVLO} which is typically 2.0V. The device starts operation once the rising V_{IN} trips V_{UVLO} threshold plus its hysteresis of 100 mV at typ. 2.1V.

THERMAL REGULATION

The TPS6125x device contains a thermal regulation loop that monitors the die temperature during the pre-charge phase. If the die temperature rises to high values of about 110 °C, the device automatically reduces the current to prevent the die temperature from increasing further. Once the die temperature drops about 10 °C below the threshold, the device will automatically increase the current to the target value. This function also reduces the current during a short-circuit condition.

THERMAL SHUTDOWN

As soon as the junction temperature, T_J , exceeds 140°C (typ.) the device goes into thermal shutdown. In this mode, the high-side and low-side MOSFETs are turned-off. When the junction temperature falls below the thermal shutdown minus its hysteresis, the device continuous the operation.

APPLICATION INFORMATION

INDUCTOR SELECTION

A boost converter normally requires two main passive components for storing energy during the conversion, an inductor and an output capacitor are required. It is advisable to select an inductor with a saturation current rating higher than the possible peak current flowing through the power switches.

The inductor peak current varies as a function of the load, the input and output voltages and can be estimated using [Equation 4](#).

$$I_{L(PEAK)} = \frac{V_{IN} \cdot D}{2 \cdot f \cdot L} + \frac{I_{OUT}}{(1-D) \cdot \eta} \quad \text{with } D = 1 - \frac{V_{IN} \cdot \eta}{V_{OUT}} \quad (4)$$

Selecting an inductor with insufficient saturation performance can lead to excessive peak current in the converter. This could eventually harm the device and reduce its reliability.

When selecting the inductor, as well as the inductance, parameters of importance are: maximum current rating, series resistance, and operating temperature. The inductor DC current rating should be greater (by some margin) than the maximum input average current, refer to [Equation 5](#) and [CURRENT LIMIT OPERATION](#) section for more details.

$$I_{L(DC)} = \frac{V_{OUT}}{V_{IN}} \cdot \frac{1}{\eta} \cdot I_{OUT} \quad (5)$$

The TPS6125x series of step-up converters have been optimized to operate with an effective inductance in the range of 0.7µH to 2.9µH and with output capacitors in the range of 10µF to 47µF. The internal compensation is optimized for an output filter of L = 1µH and C_O = 10µF. Larger or smaller inductor values can be used to optimize the performance of the device for specific operating conditions. For more details, see the [CHECKING LOOP STABILITY](#) section.

In high-frequency converter applications, the efficiency is essentially affected by the inductor AC resistance (i.e. quality factor) and to a smaller extent by the inductor DCR value. To achieve high efficiency operation, care should be taken in selecting inductors featuring a quality factor above 25 at the switching frequency. Increasing the inductor value produces lower RMS currents, but degrades transient response. For a given physical inductor size, increased inductance usually results in an inductor with lower saturation current.

The total losses of the coil consist of both the losses in the DC resistance, R_(DC), and the following frequency-dependent components:

- The losses in the core material (magnetic hysteresis loss, especially at high switching frequencies)
- Additional losses in the conductor from the skin effect (current displacement at high frequencies)
- Magnetic field losses of the neighboring windings (proximity effect)
- Radiation losses

The following inductor series from different suppliers have been used with the TPS6125x converters.

Table 4. List of Inductors

MANUFACTURER	SERIES	DIMENSIONS (in mm)
HITACHI METALS	KSLI-322512BL1-1R0	3.2 x 2.5 x 1.2 max. height
MURATA	LQM32PN1R0MG0	3.2 x 2.5 x 1.0 max. height
	LQM2HPN1R0MG0	2.5 x 2.0 x 1.0 max. height
TOKO	DFE322512C-1R0	3.2 x 2.5 x 1.2 max. height

OUTPUT CAPACITOR

For the output capacitor, it is recommended to use small ceramic capacitors placed as close as possible to the V_{OUT} and GND pins of the IC. If, for any reason, the application requires the use of large capacitors which can not be placed close to the IC, using a smaller ceramic capacitor in parallel to the large one is highly recommended. This small capacitor should be placed as close as possible to the V_{OUT} and GND pins of the IC. To get an estimate of the recommended minimum output capacitance, [Equation 6](#) can be used.

$$C_{\text{MIN}} = \frac{I_{\text{OUT}} \cdot (V_{\text{OUT}} - V_{\text{IN}})}{f \cdot \Delta V \cdot V_{\text{OUT}}} \quad (6)$$

Where f is the switching frequency which is 3.5MHz (typ.) and ΔV is the maximum allowed output ripple.

With a chosen ripple voltage of 20mV, a minimum effective capacitance of 9μF is needed. The total ripple is larger due to the ESR of the output capacitor. This additional component of the ripple can be calculated using [Equation 7](#)

$$V_{\text{ESR}} = I_{\text{OUT}} \cdot R_{\text{ESR}} \quad (7)$$

An MLCC capacitor with twice the value of the calculated minimum should be used due to DC bias effects. This is required to maintain control loop stability. The output capacitor requires either an X7R or X5R dielectric. Y5V and Z5U dielectric capacitors, aside from their wide variation in capacitance over temperature, become resistive at high frequencies. There are no additional requirements regarding minimum ESR. Larger capacitors cause lower output voltage ripple as well as lower output voltage drop during load transients but the total output capacitance value should not exceed ca. 50μF.

DC bias effect: high cap. ceramic capacitors exhibit DC bias effects, which have a strong influence on the device's effective capacitance. Therefore the right capacitor value has to be chosen very carefully. Package size and voltage rating in combination with material are responsible for differences between the rated capacitor value and it's effective capacitance. For instance, a 10μF X5R 6.3V 0603 MLCC capacitor would typically show an effective capacitance of less than 4μF (under 5V bias condition, high temperature).

In applications featuring high pulsed load currents (e.g. TPS61253 based solution) it is recommended to run the converter with a reasonable amount of effective output capacitance, for instance x2 10μF X5R 6.3V 0603 MLCC capacitors connected in parallel.

INPUT CAPACITOR

Multilayer ceramic capacitors are an excellent choice for input decoupling of the step-up converter as they have extremely low ESR and are available in small footprints. Input capacitors should be located as close as possible to the device. While a 4.7μF input capacitor is sufficient for most applications, larger values may be used to reduce input current ripple without limitations.

Take care when using only ceramic input capacitors. When a ceramic capacitor is used at the input and the power is being supplied through long wires, such as from a wall adapter, a load step at the output can induce ringing at the VIN pin. This ringing can couple to the output and be mistaken as loop instability or could even damage the part. Additional "bulk" capacitance (electrolytic or tantalum) should in this circumstance be placed between C_I and the power source lead to reduce ringing than can occur between the inductance of the power source leads and C_I.

CHECKING LOOP STABILITY

The first step of circuit and stability evaluation is to look from a steady-state perspective at the following signals:

- Switching node, SW
- Inductor current, I_L
- Output ripple voltage, $V_{OUT(AC)}$

These are the basic signals that need to be measured when evaluating a switching converter. When the switching waveform shows large duty cycle jitter or the output voltage or inductor current shows oscillations, the regulation loop may be unstable. This is often a result of board layout and/or L-C combination.

As a next step in the evaluation of the regulation loop, the load transient response is tested. The time between the application of the load transient and the turn on of the P-channel MOSFET, the output capacitor must supply all of the current required by the load. V_{OUT} immediately shifts by an amount equal to $\Delta I_{(LOAD)} \times ESR$, where ESR is the effective series resistance of C_{OUT} . $\Delta I_{(LOAD)}$ begins to charge or discharge C_{OUT} generating a feedback error signal used by the regulator to return V_{OUT} to its steady-state value. The results are most easily interpreted when the device operates in PWM mode.

During this recovery time, V_{OUT} can be monitored for settling time, overshoot or ringing that helps judge the converter's stability. Without any ringing, the loop has usually more than 45° of phase margin. Because the damping factor of the circuitry is directly related to several resistive parameters (e.g., MOSFET $r_{DS(on)}$) that are temperature dependant, the loop stability analysis has to be done over the input voltage range, load current range, and temperature range.

LAYOUT CONSIDERATIONS

For all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground tracks. The input capacitor, output capacitor, and the inductor should be placed as close as possible to the IC. Use a common ground node for power ground and a different one for control ground to minimize the effects of ground noise. Connect these ground nodes at any place close to the ground pins of the IC.

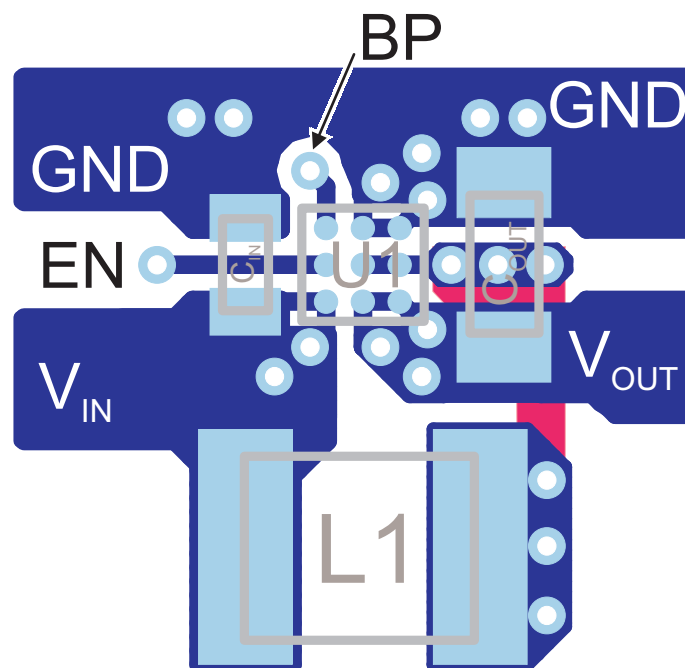


Figure 37. Suggested Layout (Top)

THERMAL INFORMATION

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance are listed below:

- Improving the power dissipation capability of the PCB design
- Improving the thermal coupling of the component to the PCB
- Introducing airflow in the system

As power demand in portable designs is more and more important, designers must figure the best trade-off between efficiency, power dissipation and solution size. Due to integration and miniaturization, junction temperature can increase significantly which could lead to bad application behaviors (i.e. premature thermal shutdown or worst case reduce device reliability).

Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists (e.g. TPS61253 or TPS61259 based solutions), special care must be paid to thermal dissipation issues in board design. The device operating junction temperature (T_J) should be kept below 125°C.

TYPICAL APPLICATION

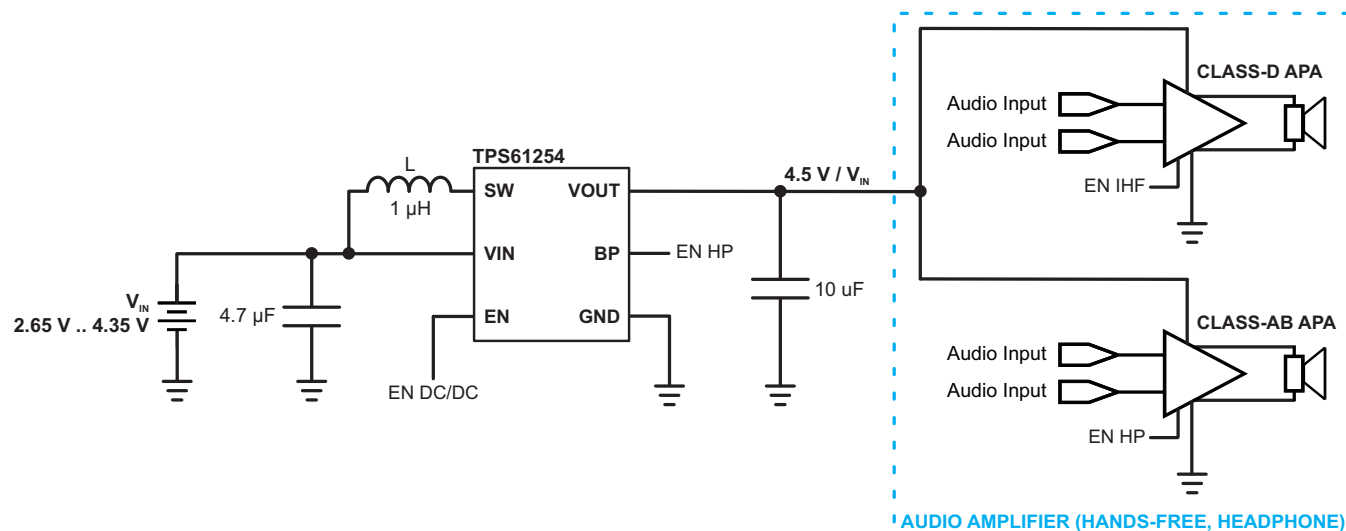


Figure 38. Combined Audio Amplifier Power Supply

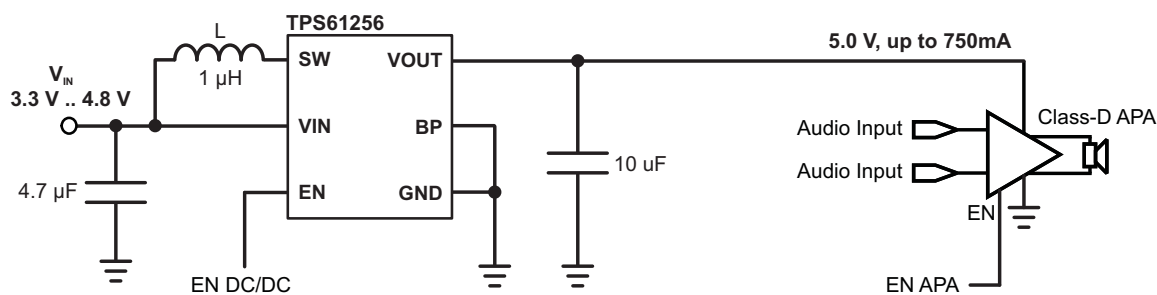


Figure 39. "Boosted" Audio Power Supply

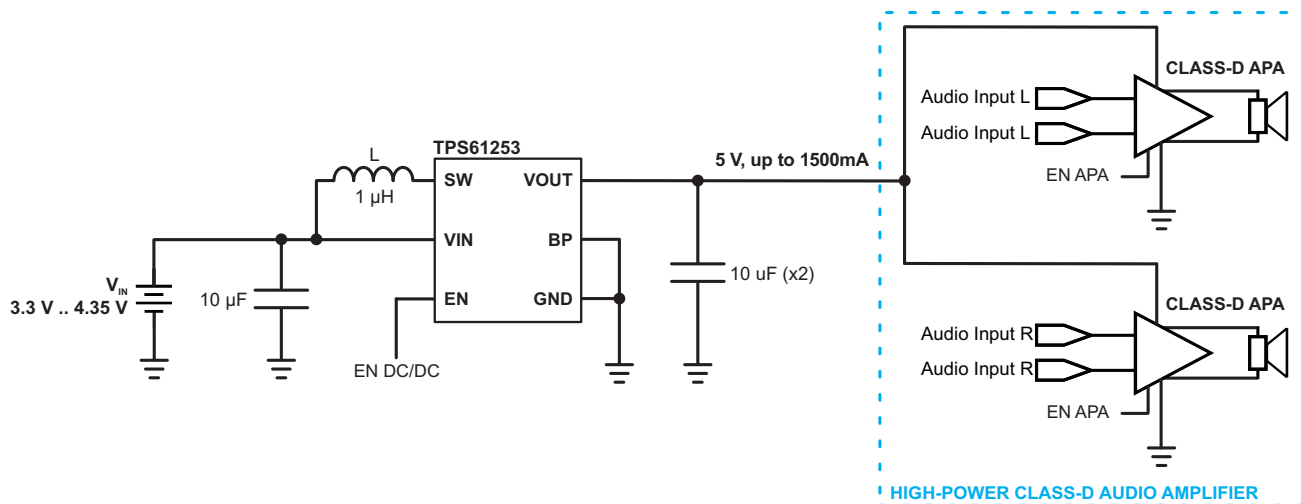
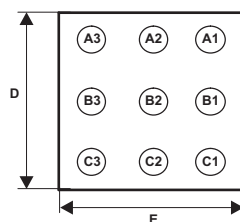


Figure 40. "Boosted" Stereo Audio Power Supply

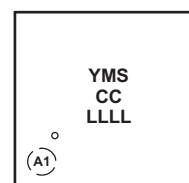


PACKAGE SUMMARY

**CHIP SCALE PACKAGE
(BOTTOM VIEW)**



**CHIP SCALE PACKAGE
(TOP VIEW)**



Code:

- YM - 2 digit date code
- S - assembly site code
- CC - chip code (see ordering table)
- LLLL - lot trace code

PACKAGE DIMENSIONS

The dimensions for the YFF-9 package are shown in [Table 5](#). See the package drawing at the end of this data sheet.

Table 5. YFF-9 Package Dimensions

Packaged Devices	D	E
TPS6125xYFF	1.206 ±0.03 mm	1.306 ±0.03 mm

REVISION HISTORY

Note: Page numbers of current revision may differ from previous versions.

Changes from Original (September 2011) to Revision A Page

- Changed device TPS61256 to production status 2

Changes from Revision A (October 2011) to Revision B Page

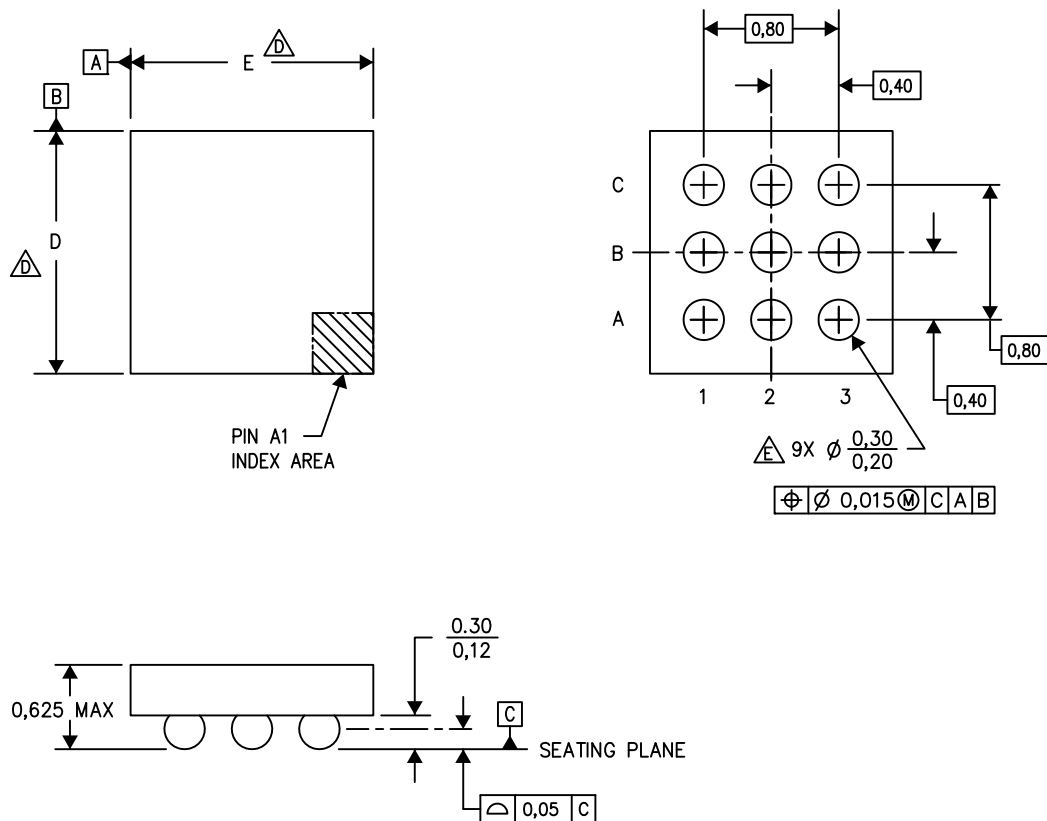
- Added TPS61253 and TPS61258 to data sheet header as production devices 1
- Changed devices TPS61253 and TPS61258 to production status 2
- Changed graphic entity for [Figure 5](#) 9
- Changed graphic entity for [Figure 12](#) 10
- Changed graphic entity for [Figure 15](#) 11
- Changed graphic entity for [Figure 25](#) 14

Changes from Revision B (May 2012) to Revision C Page

- Added TPS61259 to data sheet header as production device 1
- Changed device TPS61259 to production status 2

YFF (S-XBGA-N9)

DIE-SIZE BALL GRID ARRAY



4207625-6/AK 11/12

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.
 - \triangle The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.
 - E. Reference Product Data Sheet for array population.
 - F. This package contains Pb-free balls.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPS61253YFFR	ACTIVE	DSBGA	YFF	9	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	SBF	Samples
TPS61253YFFT	ACTIVE	DSBGA	YFF	9	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	SBF	Samples
TPS61254YFFR	ACTIVE	DSBGA	YFF	9	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	QWR	Samples
TPS61254YFFT	ACTIVE	DSBGA	YFF	9	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	QWR	Samples
TPS61256YFFR	ACTIVE	DSBGA	YFF	9	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	RAV	Samples
TPS61256YFFT	ACTIVE	DSBGA	YFF	9	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	RAV	Samples
TPS61258YFFR	ACTIVE	DSBGA	YFF	9	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	SAZ	Samples
TPS61258YFFT	ACTIVE	DSBGA	YFF	9	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	SAZ	Samples
TPS61259YFFR	ACTIVE	DSBGA	YFF	9	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	SAY	Samples
TPS61259YFFT	ACTIVE	DSBGA	YFF	9	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	SAY	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

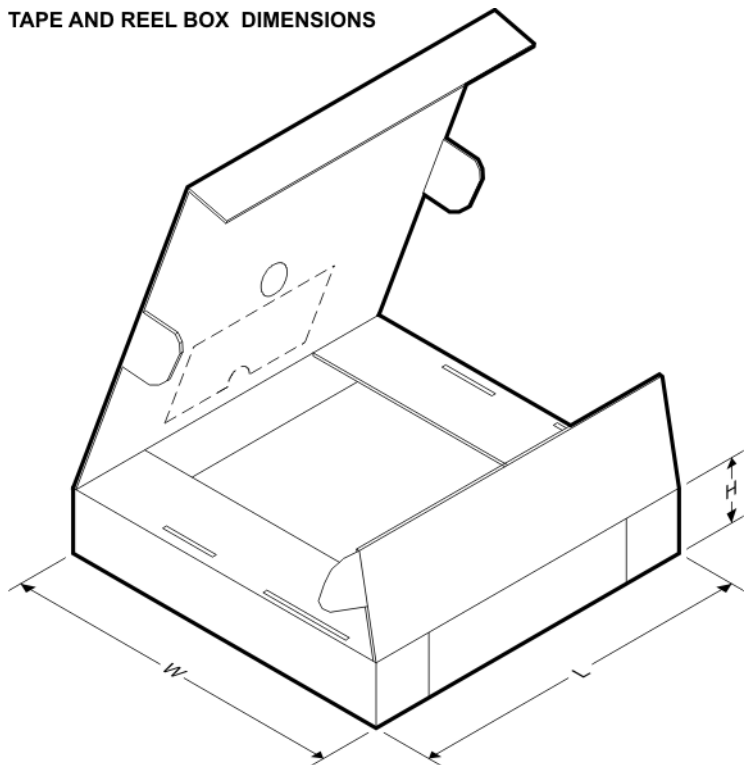
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS61253YFFT	DSBGA	YFF	9	250	180.0	8.4	1.41	1.31	0.69	4.0	8.0	Q1
TPS61254YFFT	DSBGA	YFF	9	250	180.0	8.4	1.41	1.31	0.69	4.0	8.0	Q1
TPS61256YFFR	DSBGA	YFF	9	3000	180.0	8.4	1.41	1.31	0.69	4.0	8.0	Q1
TPS61256YFFT	DSBGA	YFF	9	250	180.0	8.4	1.41	1.31	0.69	4.0	8.0	Q1
TPS61258YFFR	DSBGA	YFF	9	3000	180.0	8.4	1.41	1.31	0.69	4.0	8.0	Q1
TPS61258YFFT	DSBGA	YFF	9	250	180.0	8.4	1.41	1.31	0.69	4.0	8.0	Q1
TPS61259YFFT	DSBGA	YFF	9	250	180.0	8.4	1.41	1.31	0.69	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS61253YFFT	DSBGA	YFF	9	250	182.0	182.0	17.0
TPS61254YFFT	DSBGA	YFF	9	250	182.0	182.0	17.0
TPS61256YFFR	DSBGA	YFF	9	3000	182.0	182.0	17.0
TPS61256YFFT	DSBGA	YFF	9	250	182.0	182.0	17.0
TPS61258YFFR	DSBGA	YFF	9	3000	182.0	182.0	17.0
TPS61258YFFT	DSBGA	YFF	9	250	182.0	182.0	17.0
TPS61259YFFT	DSBGA	YFF	9	250	182.0	182.0	17.0

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com